Topics in Nanosciences End Semester Examination: Monsoon 2022

IIIT-Hyderabad

	1111-Hyderabad	Time: 3 hrs
Full Marks: 100		********
Note: Use of a non-pr	rogrammable scientific calculator is al	lowed.
**	**************	wing and justify your
	pordination numbers, answer the follo	
(i) Give the increasing order of the (r(ii) Which of the following is expect step vacancy vs. surface vacancy?(b) Why are the 'Hydrodesulfurization briefly describe its mechanism of performance?	re)activities of kink, corner, edge, and sted to be energetically less favorable: on (HDS)' catalysts so important? Namaction. How can an addition of ([3+2] e an HDS catalyst and
Q.2. In the following, the chiral vector (i) $c = 9 a_1$ (ii) $c = 9 a_2$ (iii) $c = 9a_1 + 9a_2$ (a) What is the type of nanotube form (b) Arrange these tubes in the order of (c) Which of these tubes is metallic, a	Pa ₂ (iv) c = 9a ₁ + 7a ₂ . ned in each case? Justify. If increasing diameter.	[3.5] [3] [3.5]
Q.3. (a) Mention two microscopy (repography of nanomaterials. (b) Why are high-energy electrons use (c) Name a nanoscopy technique who vacuum. (d) Mention three 'intensive properties (e) When do the size effects begin to (f) Why do the surface-interface effects the nanomaterials, unlike bulk materials.	ution + penetration ed in electron microscopy techniques? ese work environment can be air or liques? es' that do not remain 'intensive' in na appear in materials? ets play a great role in determining the	[1] [1.5] uid, not necessarily [1] nomaterials. [1.5] [1.5]
Q.4. (a) Define and explain the phothermodynamic expression.(b) What is the effect of Ostwald Riped dispersions?(c) How does the Cassie-Baxter in superhydrophobicity of a surface?	ening on the size distribution (dispersi	[1,3] (ty) of the nanoparticle [1]
Q.5. (a) Compare the mechanisms resmetal and semiconductor nanoparticle (b) Discuss the nanoparticle size ewavelength, etc., of) the LSPR (locali (c) Two colorless, odorless, and transprotein solution and the other an aquistinguish/identify them using the opappropriate theoretical relationships to	effects on the nature of (bandwidth zed surface plasmon resonance). asparent solutions are given to you: solution of the poison, potassium cyantical property of gold nanoparticles di	h, peak height, peak [3.5] one containing an aq. anide. How could you

(d) The absorption coefficients of human (aorta) ussue and of water as a function of the edwavelength shows that the minimum of the tissue absorption can be found at approximation. Some studies have suggested that multiple-photon absorption of gold nanospheroma. Some studies have suggested that multiple-photon absorption of gold nanospheromatic wavelength might be advantageous for plasmonic heating (photoinduced hyperthermia). It is absorption cross-section is several monophotonic excitation is advantageous, because its absorption cross-section is several magnitude higher than multiphotonic excitation. What morphologies/shapes of magnitude higher than multiphotonic for this purpose?	es at this However
	[1]
afm,stm Q.6. (a) Name two methods that can be applied for nanoscale distance measurements.	res can h
Q.6. (a) Name two methods that can be applied for halloscale distance measurements. (b) Describe how the assembly-disassembly property of functionalized gold nanosphe. (b) Describe how the assembly-disassembly property of functionalized gold nanosphe.	A strands
(b) Describe how the assembly-disassembly property of functionalized gold half-spile. (b) Describe how the assembly-disassembly property of functionalized gold half-spile. Used for the highly sensitive optical detection of trace amounts of sequence-specific DN. Describe the principles of this sensing methoded to blue, complimenaty dna Describe the principles of this sensing methoded to blue, complimenaty dna Describe the principles of this sensing methoded to blue, complimenated gold half-spile.	[3.5]
Describe the principles of this sensing methods. (c) Discuss the conditions for the maximum enhancement of the local field on a small	
(c) Discuss the conditions for the maximum emandement of the recent for	[2]
plasmonic nanoparticle. (d) What is "Surface-Enhanced Raman Scattering (SERS)"? Describe its mechanisms.	[3.5]
Q.7. (a) Show the full-loop hysteresis curves for ferromagnetic, paramagnet	tic, and
superparamagnetic materials on the same plot. Show all the cardinal points M_s , M_r , and	H _c on the
hysteresis curves Compare the salient features of the plots.	[3]
(b) Draw a schematic plot showing the variation of the coercivity of a ferromagnetic partie	cle with
its size. Justify the nature of the variation.	[3]
(c) Show that a particle acts superparamagnetically on the 100 s experimental timescale	it it has a
volume smaller than the critical volume, $V_{sp} = 25kT_B/K$ (the terms have their usual mean	ings). [4]
Q.8. (a) Why is Giant Magnetoresistance (GMR) a quantum mechanical and a nanoscale	
Q.8. (a) Why is Giant Magnetoresistance (GMA) a quantum mechanical and a nanoscale	[1.5]
(b) How does the construction of a spin valve differ from the magnetic tunneling junction devices?	
(c) Discuss the mechanism (with the help of a schematic diagram) of a GMR device com-	posed of
the nanoscale ferromagnetic layers of cobalt separated by the nanoscale nonmagnetic copper.	layer of [4]
(d) "Currently, the best technology of 'Read' sensors employ the GMR effect." Briefly	
how the GMR effect is used in the 'Reading' head for information retrieval.	[2]
Q.9. (a) Derive an expression that shows how the density of states (DOS) function dependent	
energy of a 1D material.	[5]
(b) Show that the quantum of electrical conductance is given by $\frac{2e^2}{h}$.	[3]
(c) If there exists a finite nonzero resistance in a nano-conductor, why does a superconductor	tor have
zero resistance?	[2]
Se faingle electron transistor (SET)	[1]
Q.10. (a) Mention two advantages of a 'single-electron transistor (SET)'. (b) Discuss the construction and working principles of a typical SET.	[1+3.5]
(c) Calculate the size (radius in nm) of a sphere-shaped Si quantum dot that would pro-	duce an
observable single electron effect at room temperature (300 K). Given: Dielectric constant 11.5; Permittivity of vacuum = 8.85×10^{-12} F.m ⁻¹ ; $k = 1.38 \times 10^{-23}$ JK ⁻¹ ; 1 eV = 1.602×10^{-12} JK ⁻¹	t of Si =
11.5, reminitivity of vacuum 5.55 x 10 1.56 x 10 JK, 1 ey = 1.002 x 10	[4.5]
	[7.5]